

# DCR780G30

#### Replaces DS6045-1

# **Phase Control Thyristor**

DS6045-2 June 2019	(LN38865)
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#### **FEATURES**

- Double Side Cooling
- High Surge Capability

**High Power Drives** 

**Static Switches** 

**VOLTAGE RATINGS** 

Part and

Ordering

Number

DCR780G30

DCR780G28

DCR780G26

DCR780G24

**High Voltage Power Supplies** 

Repetitive Peak

Voltages

V<sub>DRM</sub> and V<sub>RRM</sub> V

3000

2800

2600

2400

Conditions

 $T_{vi} = -40^{\circ}C$  to 125°C,

 $I_{DRM} = I_{RRM} = 60 \text{mA},$ 

V<sub>DSM</sub> & V<sub>RSM</sub> = V<sub>DRM</sub> & V<sub>RRM</sub> +100V respectively

 $V_{\text{DRM}}$ ,  $V_{\text{RRM}}$   $t_{p}$  = 10ms,

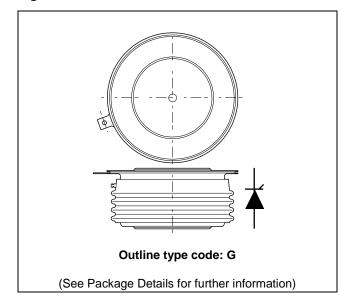
**APPLICATIONS** 

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#### **KEY PARAMETERS**

	3000 V
I <sub>T(AV)</sub>	780 A
I <sub>TSM</sub>	10500 A
dV/dt*	1000 V/µs
dl/dt	200 A/µs

#### \* Higher dV/dt selections available



Lower voltage grades available.

#### ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

#### DCR780G30

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order. Fig. 1 Package outline

### **CURRENT RATINGS**

 $T_{case} = 60^{\circ}C$  unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load	780	А
I <sub>T(RMS)</sub>	RMS value	-	1220	А
Ι <sub>Τ</sub>	Continuous (direct) on-state current	-	1100	А

### SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, $T_{case} = 125^{\circ}C$	10.5	kA
l <sup>2</sup> t	I <sup>2</sup> t for fusing	$V_R = 0$	0.551	MA <sup>2</sup> s

### THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	S	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	DC	-	0.035	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.008	°C/W
$T_{vj}$	Virtual junction temperature	Blocking V <sub>DRM</sub> / <sub>VRRM</sub>		-	125	°C
T <sub>stg</sub>	Storage temperature range			-40	140	°C
Fm	Clamping force			12	18	kN

## **DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditio	ons	Min.	Max.	Units
I <sub>RRM</sub> /I <sub>DRM</sub>	Peak reverse and off-state current	At V <sub>RRM</sub> /V <sub>DRM</sub> , T <sub>case</sub> = 125°C		-	60	mA
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V <sub>DRM</sub> , T <sub>j</sub> = 125°C, gate open		1000	-	V/µs
dl/dt	Rate of rise of on-state current	From 67% V <sub>DRM</sub> to 1000A	Repetitive 50Hz	-	200	A/µs
		Gate source 30V, $10\Omega$ ,	Non-repetitive	-	1000	A/µs
		t <sub>r</sub> < 0.5µs, T <sub>j</sub> = 125°C				
V <sub>T</sub>	On-state voltage	I <sub>T</sub> = 1500A, T <sub>case</sub> = 125°C			1.90	V
V <sub>T(TO)</sub>	Threshold voltage – Low level	T <sub>case</sub> = 125°C		-	1.00	V
۲ <sub>T</sub>	On-state slope resistance – Low level	T <sub>case</sub> = 125°C		-	0.60	mΩ
t <sub>gd</sub>	Delay time	$V_D = 67\% V_{DRM}$ , gate source	30V, 10Ω	-	3.0	μs
		$t_r = 0.5 \mu s, T_j = 25^{\circ}C$				
tq	Turn-off time	$T_j = 125^{\circ}C, V_R = 100V, dl/dt$	= 10A/µs,		400	μs
		$dV_{DR}/dt = 20V/\mu s$ linear to 67	7% V <sub>DRM</sub>	-		
$Q_S$	Stored charge	$I_{T} = 1000A, tp = 1000us, T_{j} = 125^{\circ}C, dI/dt = 10A/\mu s,$		-	2400	μC
I <sub>RR</sub>	Reverse recovery current			-	125	А
١L	Latching current	$T_j = 25^{\circ}C,$		-	1	А
Iн	Holding current	T <sub>j</sub> = 25°C,		-	200	mA

# GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V <sub>GT</sub>	Gate trigger voltage	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	3	V
V <sub>GD</sub>	Gate non-trigger voltage	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	0.3	V
I <sub>GT</sub>	Gate trigger current	$V_{DRM} = 5V, T_{case} = 25^{\circ}C$	300	mA
I <sub>GD</sub>	Gate non-trigger current	At 40% V <sub>DRM</sub> , T <sub>case</sub> = 125°C	20	mA

### CURVES

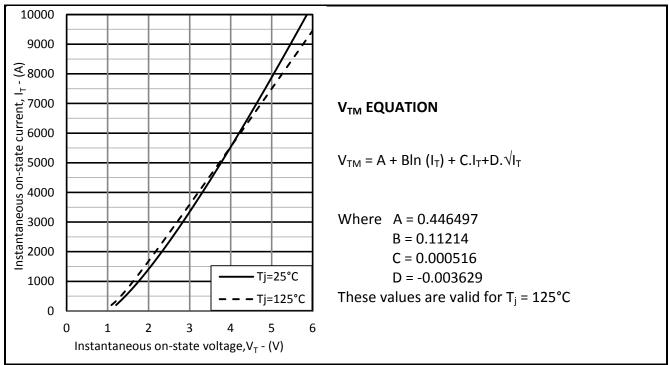


Fig.2 Maximum & minimum on-state characteristics

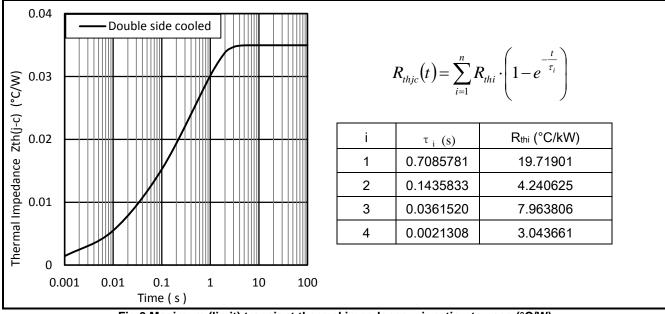
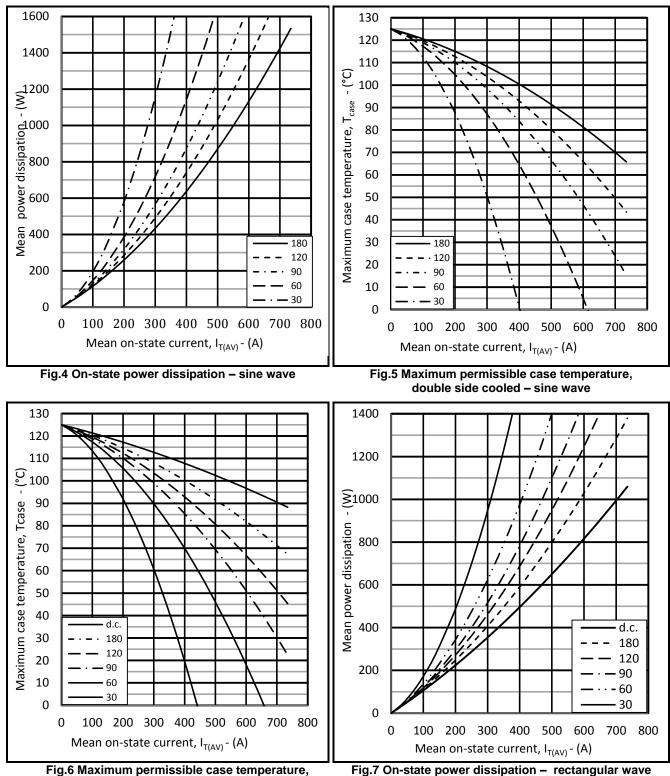


Fig.3 Maximum (limit) transient thermal impedance - junction to case (°C/W)



double side cooled - rectangular wave



### DCR780G30

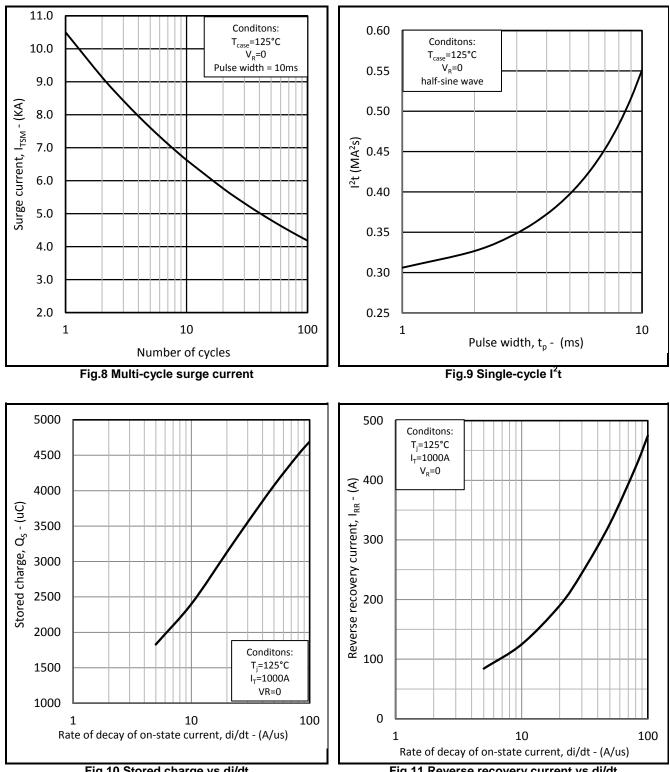


Fig.10 Stored charge vs di/dt

Fig.11 Reverse recovery current vs di/dt

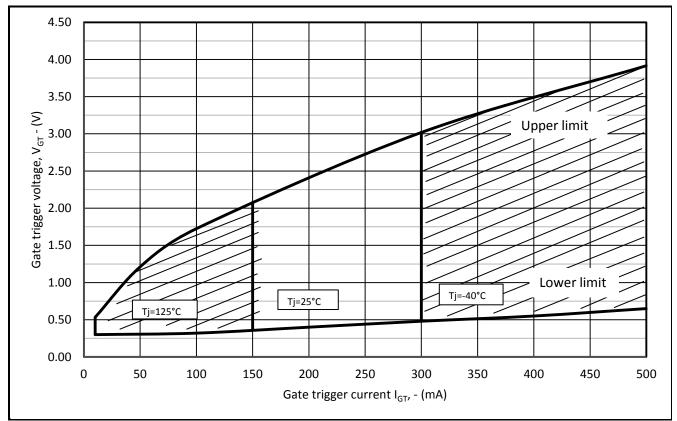


Fig.12 Gate characteristics

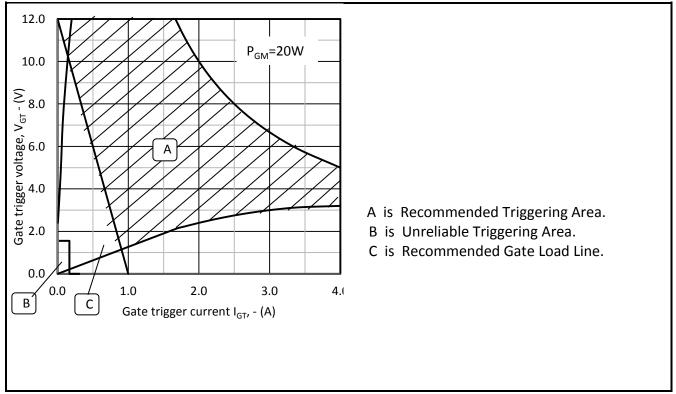


Fig.13 Gate characteristics

### PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

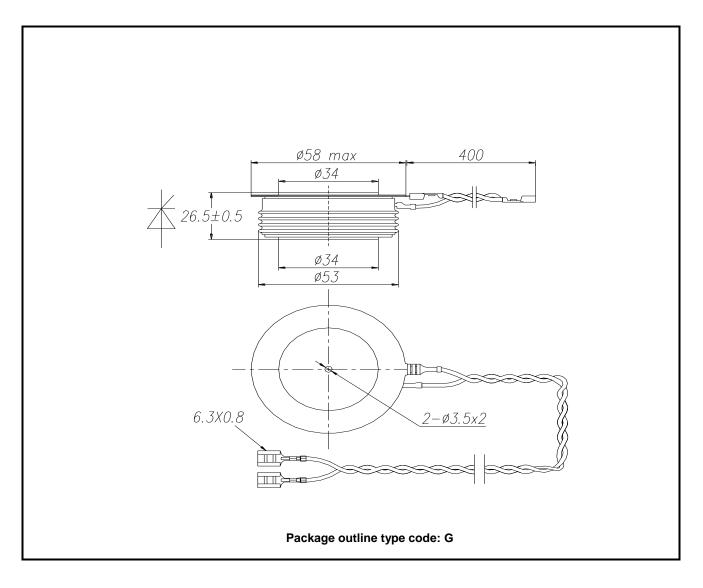


Fig.14 Package outline

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